

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## *UTV080*

8 Watts, 26.5 Volts, Class A UHF Television - Band IV & V

### **GENERAL DESCRIPTION**

The UTV 080 is a COMMON EMITTER transistor capable of providing 8 Watt Peak, Class A, RF Output Power over the band 470 - 860 MHz. The transistor includes double input prematching for full broadband capability. Gold Metalization and Diffused Ballasting are used to provide high reliability and supreme ruggedness.

### ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C 65 Watts

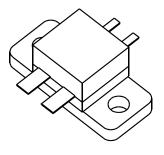
**Maximum Voltage and Current** 

BVcesCollector to Emitter Voltage50 VoltsBVceoCollector to Emitter Voltage28 VoltsBVeboEmitter to Base Voltage3.5 VoltsIcCollector Current2.5 Amps

#### **Maximum Temperatures**

Storage Temperature  $-65 \text{ to} + 150^{\circ}\text{C}$ Operating Junction Temperature  $+200^{\circ}\text{C}$ 

# CASE OUTLINE 55JV, STYLE 2



### ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg IMD¹ VSWR <sub>1</sub>	Power Out - Pk Sync Power Input Power Gain Intermodulation Distortion Load Mismatch Tolerance	F = 470 - 860 MHz Vcc = 26.5 Volts Ic = 1.7 Amps Pref = 8 Watts F = 860 MHz	8	10	1.0 -58 3:1	Watts Watts dB dB

LVceo <sup>2</sup>	Collector to Emitter Breakdown	Ic = 60  mA	28		Volts
BVces <sup>2</sup>	Collector to Base Breakdown	Ic = 20  mA	50		Volts
BVebo <sup>2</sup>	Emitter to Base Breakdown	Ie = 5  mA	3.5		Volts
$\mathbf{h_{FE}}^2$	Current Gain	Vce = 5 V, 500 mA	10		
Cob <sup>2</sup>	Output Capacitance	Vcb = 26 V, F = 1 MHz			pF
θјс	Thermal Resistance	$Tc = 25^{\circ}C$		2.5	°C/W

Note 1: F1=860 MHz, F2=863.5 MHz, F3=864.5 Mhz

European test method, Vision = -8dB, Sideband= -16dB, Sound = -7 dB

2: Per side

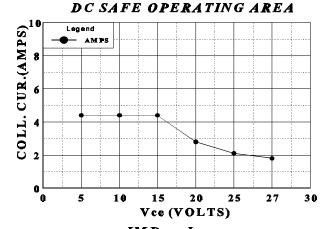
Initial Issue June, 1994

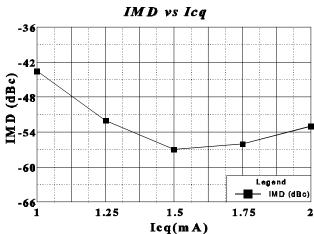
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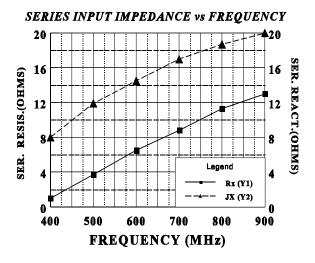
GHz Technology Inc. 3000 Oakmead Village Drive, Santa Clara, CA 95051-0808 Tel. 408 / 986-8031 Fax 408 / 986-8120

### **UTV080**

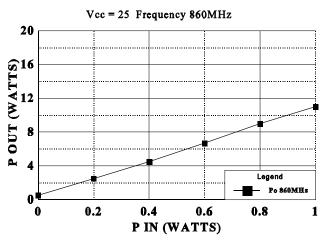


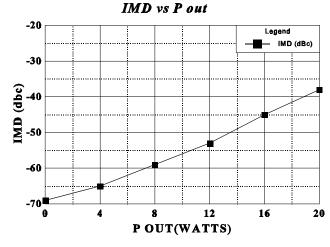




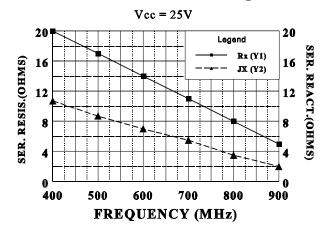


### **POWER OUTPUT vs POWER INPUT**





### SERIES LOAD IMPEDANCE vs FREQUENCY



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